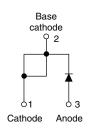


Vishay Semiconductors

Schottky Rectifier, 6 A

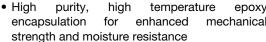


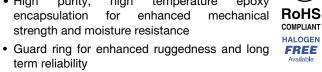


PRODUCT SUMMARY					
Package	TO-220AC				
I _{F(AV)}	6 A				
V_{R}	35 V, 40 V, 45 V				
V _F at I _F	0.53 V				
I _{RM} max.	7 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Single die				
E _{AS}	8 mJ				

FEATURES

- 175 °C T_J operation
- · High frequency operation
- · Low forward voltage drop







- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-6TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	6	Α				
V _{RRM}	Range	35 to 45	V				
I _{FSM}	t _p = 5 μs sine	690	Α				
V _F	6 A _{pk} , T _J = 125 °C	0.53	V				
T _J	Range	- 55 to 175	°C				

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS- 6TQ035PbF	VS- 6TQ035-N3	VS- 6TQ040PbF	VS- 6TQ040-N3	VS- 6TQ045PbF	VS- 6TQ045-N3	UNITS	
Maximum DC reverse voltage	V _R								
Maximum working peak reverse voltage	V _{RWM}	35	35	40	40	45	45	V	

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS			
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 164 °C	6	А				
Maximum peak one cycle non-repetitive surge current	l=a	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	690	А			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	140				
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.20 \text{A}, L = 11$	8	mJ				
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	1.20	А				



VS-6TQ...PbF Series, VS-6TQ...-N3 Series

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS				
Maximum forward voltage drop See fig. 1		6 A	T _{.1} = 25 °C	0.60	V		
	V _{FM} ⁽¹⁾	12 A	1J=25 C	0.73			
	V _{FM} ('')	6 A	T 105 °C	0.53			
		12 A	- T _J = 125 °C	0.64			
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Datady	0.8	mA		
See fig. 2	IRM ("/	T _J = 125 °C	V _R = Rated V _R	7	IIIA		
Threshold voltage	V _{F(TO)}	T T mayimum		0.35	V		
Forward slope resistance	r _t	$T_J = T_J$ maximum		18.23	mΩ		
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		400	pF		
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		8	nH		
Maximum voltage rate of change	dV/dt	Rated V _R	Rated V _R				

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and stort temperature range	rage	T _J , T _{Stg}		- 55 to 175	°C		
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	2.2	°C/W		
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	C/VV		
Approximate weight				2	g		
Approximate weight				0.07	OZ.		
Maunting targue	minimum			6 (5)	kgf · cm		
Mounting torque maximum				12 (10)	(lbf \cdot in)		
Marking device				6TQ035			
			Case style TO-220AC	6TQ040			
				6TQ	045		

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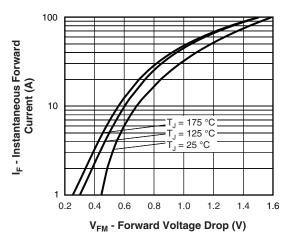


Fig. 1 - Maximum Forward Voltage Drop Characteristics

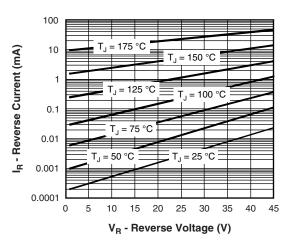


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

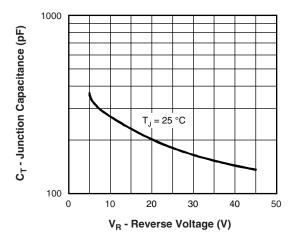


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

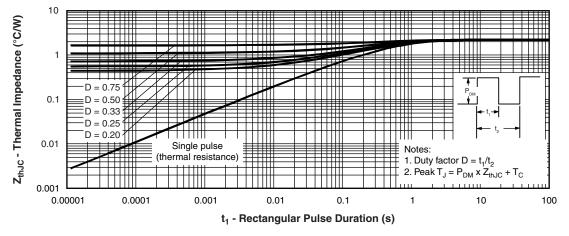


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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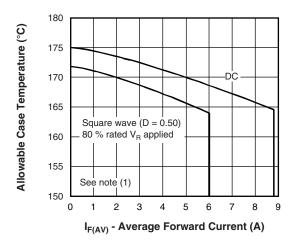


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

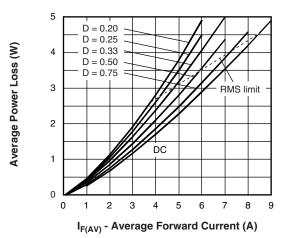


Fig. 6 - Forward Power Loss Characteristics

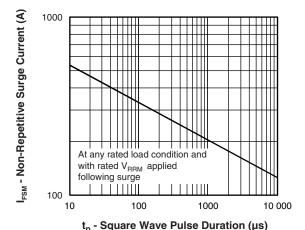


Fig. 7 - Maximum Non-Repetitive Surge Current

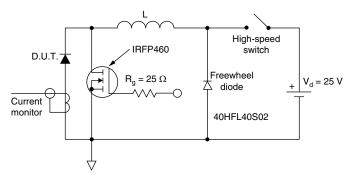


Fig. 8 - Unclamped Inductive Test Circuit

Note

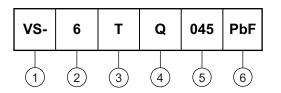
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

VS-6TQ...PbF Series, VS-6TQ...-N3 Series

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (6 = 6 A)

3 - Package:

T = TO-220

- Schottky "Q" series

035 = 35 V

Voltage ratings

040 = 40 V 045 = 45 V

6

Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-6TQ035PbF	50	1000	Antistatic plastic tube				
VS-6TQ035-N3	50	1000	Antistatic plastic tube				
VS-6TQ040PbF	50	1000	Antistatic plastic tube				
VS-6TQ040-N3	50	1000	Antistatic plastic tube				
VS-6TQ045PbF	50	1000	Antistatic plastic tube				
VS-6TQ045-N3	50	1000	Antistatic plastic tube				

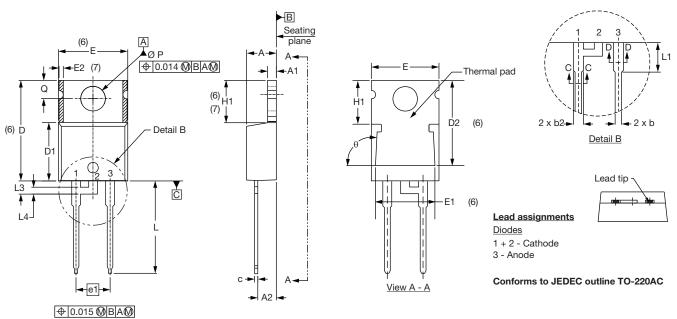
LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95221</u>					
Dort marking information	TO-220AC PbF	www.vishay.com/doc?95224			
Part marking information	TO-220AC -N3	www.vishay.com/doc?95068			



Vishay Semiconductors

TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIM	IETERS	INCHES		NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
L3	1.78	2.13	0.070	0.084	
L4	0.76	1.27	0.030	0.050	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° t	o 93°	90° t	o 93°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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SBAT54CWT1G SBM30-03-TR-E SK32A-LTP SK33A-TP SK34A-TP SK34B-TP SMD1200PL-TP ACDBN160-HF SS3003CH-TL-E
STPS30S45CW PDS3100Q-7 GA01SHT18 CRS10I30A(TE85L,QM MBR1240MFST1G MBRB30H30CT-1G BAS28E6433HTMA1 BAS
70-02L E6327 HSB123JTR-E JANTX1N5712-1 VS-STPS40L45CW-N3 DD350N12K SB007-03C-TB-E SB10015M-TL-E SB1003M3-TL-E SK110-LTP SK154-TP SK32A-TP SK33B-TP